

# **μPC251 / 1458**

## **General Purpose Dual Operational Amplifiers**

### **GENERAL DESCRIPTION**

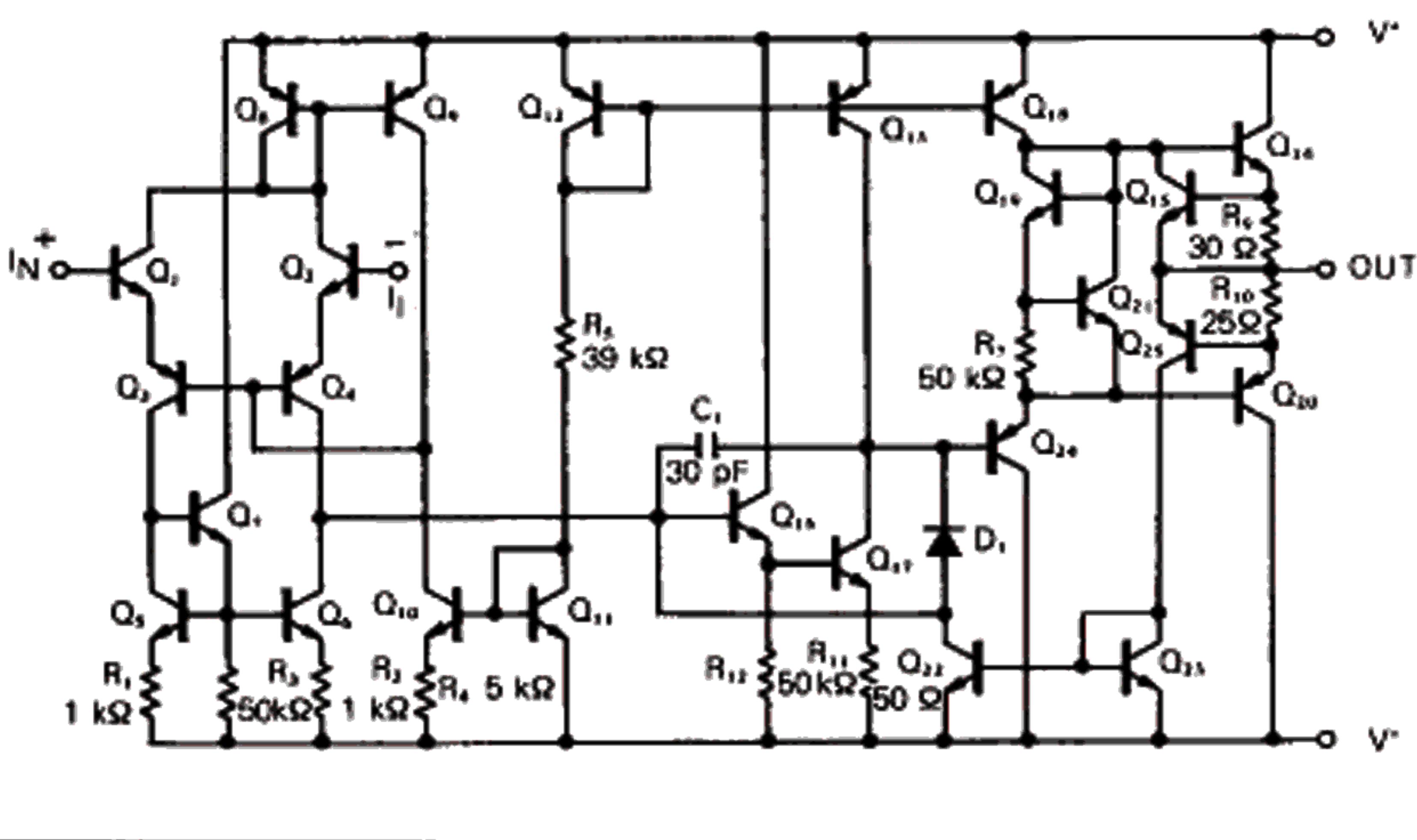
The μPC251 and 1458 are dual general purpose operational amplifiers having internal frequency compensating circuits. It is intended for a wide range of analog applications. High common mode voltage range and no latch up tendencies make this amplifier ideal for use as a voltage follower.

Two kinds of ICs are available according to reliability, the μPC251 for industry, the μPC1458 for commercial.

### **FEATURES**

- Dual μPC151/741 Internally Frequency Compensated Operational Amplifier
- Short Circuit Protection
- Large Common Mode and Differential Input Voltage
- No Latch Up
- MC1458 Direct Replacement

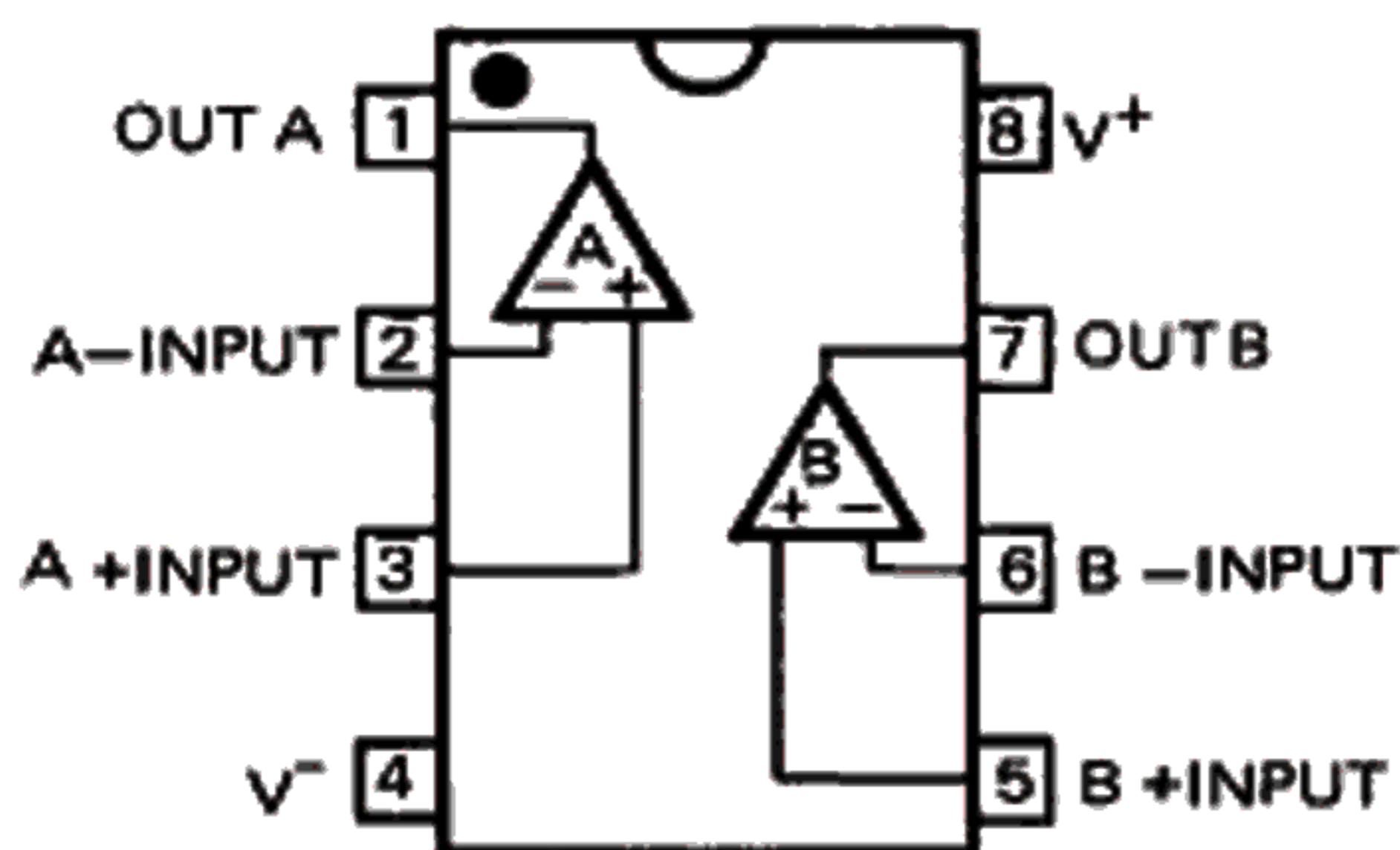
### **EQUIVALENT CIRCUIT**

**1/2 CIRCUIT**

### **ORDERING INFORMATION**

**μPC251D**8 pin Ceramic DIP  
(Dual In-Line Package)**μPC251C/μPC1458C**8 pin Plastic Molded DIP  
(Dual In-Line Package)**μPC251G/μPC1458G**8 pin Plastic Molded Flat  
Package (MINI FLAT IC)

### **CONNECTION DIAGRAM (Top View)**


**μPC251D**  
**μPC251C/μPC251G**  
**μPC1458C/μPC1458G**

ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

PARAMETER		μPC251	μPC1458	UNIT
Voltage between $V^+$ and $V^-$		36	36	V
Power Dissipation*	D Package	500	—	mW
	C Package	350	350	
	G Package	440	440	
Differential Input Voltage		±30	±30	V
Input Voltage (Note 1)		±15	±15	V
Output Short Circuit Duration		Indefinite	Indefinite	s
Operating Temperature Range	D Package	−20 to +80	—	°C
	C or G Package	−20 to +70	0 to +70	
Storage Temperature Range	D Package	−55 to +150	—	°C
	C or G Package	−55 to +125	−55 to +125	

Note 1: For supply voltages less than ±15 V, the absolute maximum input voltage is equal to the supply voltage.

\* See thermal information in chapter 11.

ELECTRICAL CHARACTERISTICS ( $V^\pm = \pm 15\text{ V}$ ,  $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Input Offset Voltage		1.0	6.0	mV	$R_s \leq 10\text{ k}\Omega$
Average Input Offset Voltage Drift		3		$\mu\text{V}/^\circ\text{C}$	$R_s \leq 10\text{ k}\Omega$
Input Offset Current		20	200	nA	
Input Bias Current		80	500	nA	
Large Signal Voltage Gain	20,000	160,000			$R_L \geq 2\text{ k}\Omega$ , $V_o = \pm 10\text{ V}$
Channel Separation		120		dB	$f = 10\text{ Hz}$ , $R_L = 2\text{ k}\Omega$
Supply Current		3.0	5.6	mA	
Power Consumption		90	170	mW	
Common Mode Rejection Ratio	70	90		dB	$R_s \leq 10\text{ k}\Omega$
Supply Voltage Rejection Ratio		30	150	$\mu\text{V/V}$	$R_s \leq 10\text{ k}\Omega$
Output Voltage Swing	±12	±14		V	$R_L \geq 10\text{ k}\Omega$
Output Voltage Swing	±10	±13		V	$R_L \geq 2\text{ k}\Omega$
Input Impedance	0.3	1.0		MΩ	

TYPICAL PERFORMANCE CHARACTERISTICS ( $T_a=25^\circ\text{C}$ )

